AMENDMENTS TO THE CLAIMS

- 1. (Original) A system comprising:
 - a chamber configured to house a substrate for processing;
 - an energy source coupled to the chamber;
- a system controller configured to control the introduction of at least two metal constituents to a focused ion beam and to control the introduction of the focused ion beam; and
- a memory coupled to the controller comprising a computer-readable medium having a computer-readable program embodied therein for directing operation of the system, the computer-readable program comprising:

instructions for controlling the energy source and for introducing the metal constituents by one of:

- (1) mixing the at least two metal constituents and introducing the at least two metal constituents into a chamber in which a focused ion beam contacts the at least two metal constituents to form a first alloy layer over a substrate;
- (2) introducing at about the same time at least two precursor gas sources in which each precursor gas source contains a respective one of the at least two metal constituents and the focused ion beam contacts the at least two precursor gases to form a first alloy layer over a substrate, and
- (3) forming a first layer of a first of the at least two metal constituents and a second layer of a second of the at least two metal constituents to create a multi-metal layer and performing one of thermal treatment and introducing focused ion beam to at least a portion of the multi-metal layer to form a first alloy layer over a substrate.
- 2. (Original) The system of claim 1, wherein each of the at least two metal constituents is selected from the group consisting of cobalt, metal carbonyl, molybdenum and tungsten.

- 3. (Original) The system of claim 2, further comprising: forming more than one alloy layer, wherein a second alloy layer is formed over the first alloy layer.
- 4. (Original) The system of claim 3, wherein the second alloy layer is created from a second multi-metal layer which is exposed to an alloy process.
- 5. (Original) The system of claim 4, wherein the alloy process involves the second multimetal layer exposed to one of a thermal treatment and to a focused ion beam.
- 6. (Withdrawn) A machine readable storage medium containing executable program instructions which when executed cause a system to perform a method comprising: controlling introduction of at least two metal constituents into a chamber; controlling a formation of an alloy from the at least two metal constituents by controlling one of:
- (1) introducing the at least two metal constituents into a chamber in which a focused ion beam contacts the two metal constituents to form a first alloy layer over a substrate;
- (2) introducing at about the same time at least two precursor gas sources in which each precursor gas source contains a respective one of the at least two metal constituents and the focused ion beam contacts the at least two precursor gases to form a first alloy layer over the substrate, and
- (3) forming a first layer of a first of the at least two metal constituents and a second layer of a second of the at least two metal constituents a multi-metal layer and performing one of thermal treatment and introducing focused ion beam to at least a portion of the multi-metal layer to form a first alloy layer over a substrate.
- 7. (Withdrawn) The machine readable storage medium of claim 6, the method further comprises:

forming more than one alloy layer, wherein a second alloy layer is formed over the first alloy layer.

- 8. (Withdrawn) The machine readable storage medium of claim 6, wherein the method further comprises:
 - controlling a formation of a second alloy layer over the substrate.
- 9. (Withdrawn) The machine readable storage medium of claim 6, wherein each of the at least two metal constituents is selected from the group consisting of cobalt, metal carbonyl, molybdenum, and tungsten.
- 10. (Withdrawn) The method of claim 8, wherein the method further comprises: an alloy process to the second alloy layer.
- 11. (Withdrawn) The machine readable storage medium of claim 10, wherein the alloy process is one of thermal treatment and applying a focused ion beam to the second alloy layer.